

/ Descriptions

SOT-323 NPN Silicon NPN transistor in a SOT-323 Plastic Package.

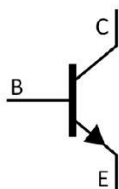
/ Features

- $V_{ce(sat)}=0.3V_{max}$
Collector to emitter saturation voltage $V_{ce(sat)}=0.3V_{max}$ Excellent lineality of DC forward current gain, Supper mini package for easy mounting.

/ Applications

For hybrid IC, small type machine low frequency voltage amplify application.

/ Equivalent Circuit



/ Pinning



PIN1 Emitter PIN 2 Base PIN 3 Collector

/ Marking

h_{FE} Classifications Symbol	Q	R	S	T
h_{FE} Range	120~270	180~390	270~560	390~820
Marking	HQH	HRH	HHS	HHT

Parameter	Symbol	Rating	Unit
Collector to Base Voltage	V_{CBO}	50	V
Collector to Emitter Voltage	V_{CEO}	50	V
Emitter to Base Voltage	V_{EBO}	6	V
Collector Current - Continuous	I_C	2SC4155 0.1	A
		2SC4155A 0.2	
Collector Power Dissipation	P_C	150	mW
Junction Temperature	T_j	125	°C
Storage Temperature Range	T_{stg}	-55~150	°C

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Collector to Base Breakdown Voltage	V_{CBO}	$I_C=0.1mA$ $R_{BE}=\infty$	50			V
Collector Cut-Off Current	I_{CBO}	$V_{CB}=50V$ $I_E=0$			0.5	A
					0.1	
Emitter Base Cut-Off Current	I_{EBO}	$V_{EB}=4V$ $I_C=0$			0.1	A

DC Current Gain $h_{FE(1)}$

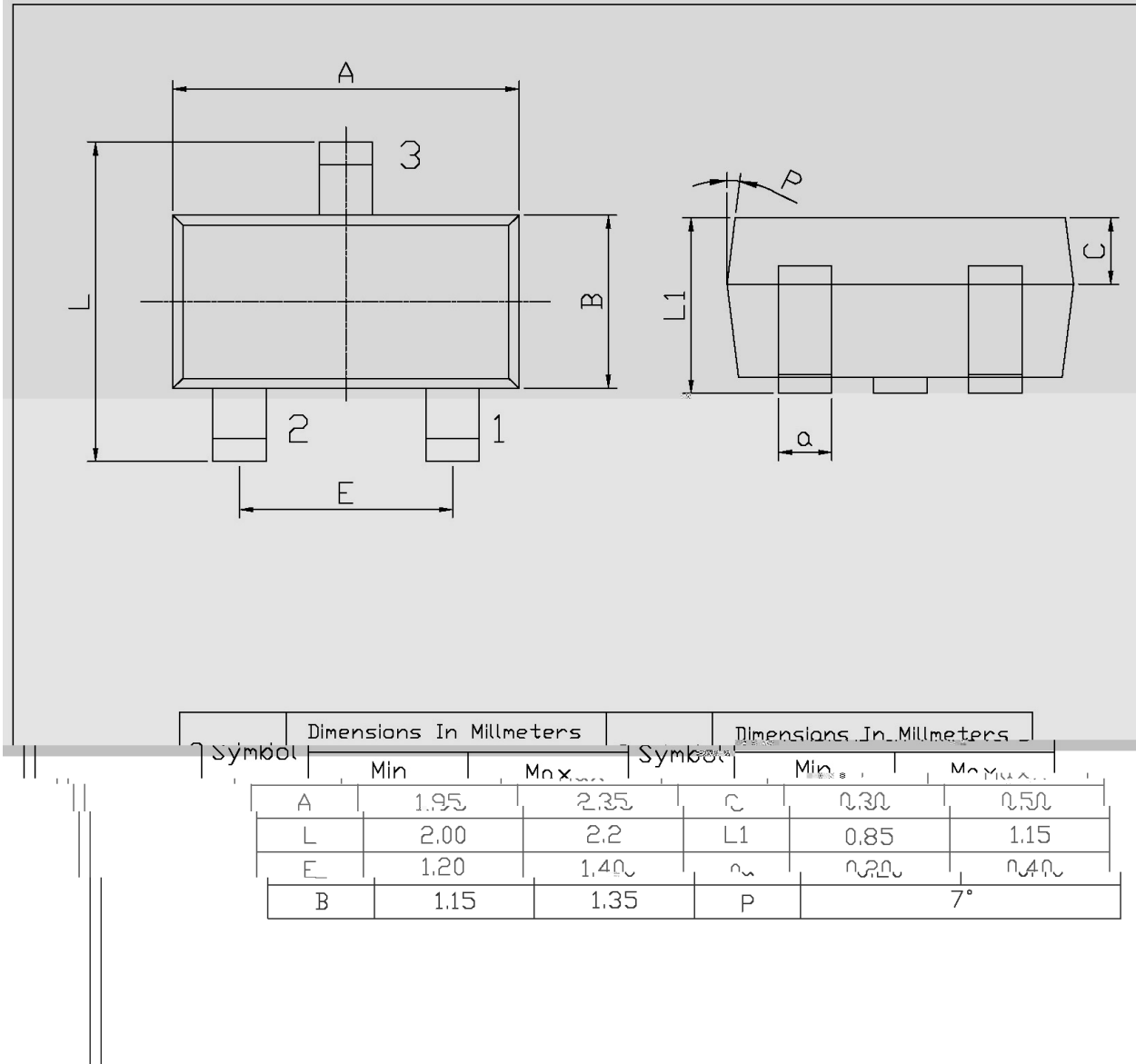
/ Electrical Characteristic Curve



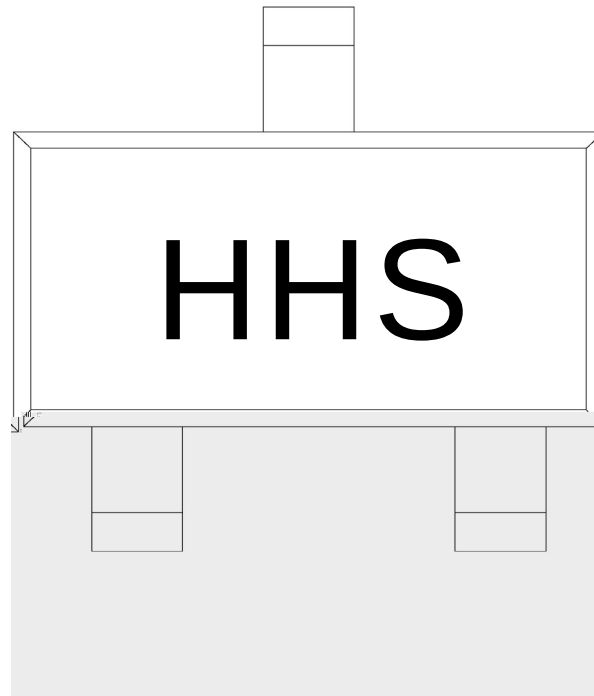
/ Package Dimensions

SOT-323

单位: mm



/ Marking Instructions



H

H

S h_{FE}

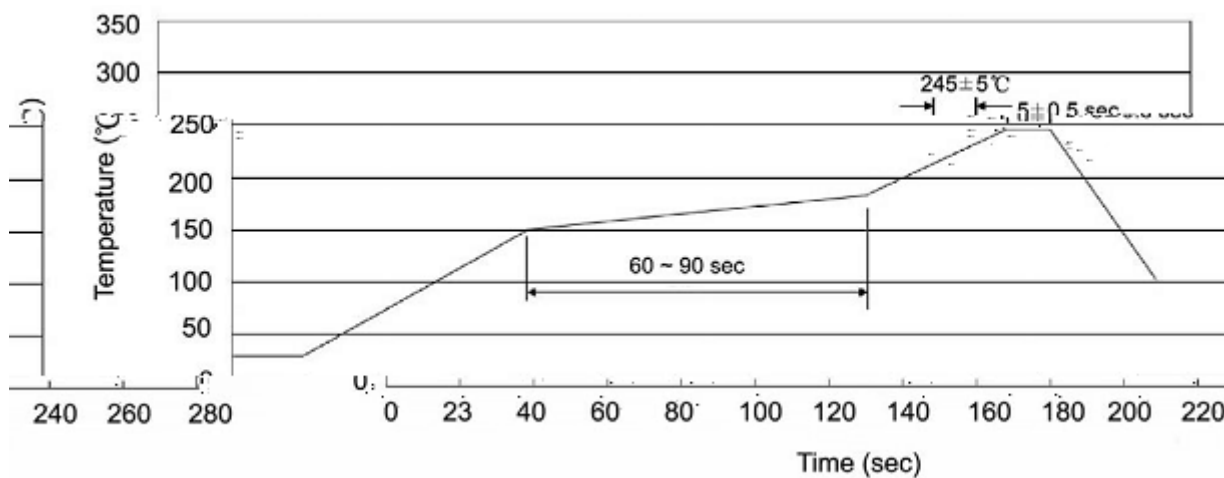
Note:

H: Company Code.

H: Product Type.

S: h_{FE} Classifications Symbol

() / Temperature Profile for IR Reflow Soldering(Pb-Free)



Note:

- | | | | | | |
|---|-------|-----|-----------|--------|---|
| 1 | 25 | 150 | 60 | 90sec; | 1.Preheating:25~150 , Time:60~90sec. |
| 2 | 245±5 | | 5±0.5sec; | | 2.Peak Temp.:245±5 , Duration:5±0.5sec. |
| 3 | | 2 | 10 | /sec. | 3. Cooling Speed: 2~10 /sec. |

/ Resistance to Soldering Heat Test Conditions

260±5 10±1 sec. Temp.:260±5℃ Time:10±1 sec

/ Packaging SPEC.

/ REEL

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm ³)		
	只 卷盘	卷盘 盒	只 盒	盒 箱	只 箱		盒	箱
						"		

/ Notices